SIC SCHOTTKY DIODE TYPE 2×100A

Preliminary

Features

- High surge current capable
- High bandwidth
- Zero reverse recovery current VDC
- Isolation type package
- Temperature Independent Switching Behavior
- 650 V
- 2×100 A • **I**F (Tc<135°C)

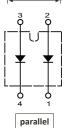
Benefits

- Unipolar rectifier
- Zero switching loss
- Smaller heat sink
- Parallel devices without thermal runaway
- Higher efficiency

Applications

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Power factor correction
- Diode snubber
- Automotive
- induction heating
- Welding equipment

Maximum Ratings



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Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×100-065P1B	650V	650V

Operating Junction Temperature : - 55 $^{\circ}$ C to +175 $^{\circ}$ C

Storage Temperature : $-55 \,^{\circ}\text{C}$ to $+175 \,^{\circ}\text{C}$

Maximum Rating	Symbol	Conditions	Value	Unit	
Continuous forward current (per diode)	I _F	T _C =135 °C	100		
Surge non-repetitive forward current	I _{FSM}	$T_{\rm C}$ =25 °C, $t_{\rm p}$ =8.3 ms	800		
sine halfwave (per diode)	·F3W	T _C =150 °C, t _p =8.3 ms	500	Α	
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t_p =10 μ s	, t _p =10 μs 3200		
(per diode)		T_{C} =150 °C, t_{p} =10 μ s	2000		
Repetitive peak reverse voltage	V_{RRM}	T _j =25 °C	650	V	
Isolation voltage between All Terminals and Baseplate	V _{iso}	50/60 Hz, t=1min I _{ISOL} ≤ 1mA	2500	V	
Mounting torque		To heatsink	1.3	Nm	
incartaing torquo		To terminal	1.1		

DIMENSIONS						
	INCHES		M	М		
	MIN	MAX	MIN	MAX		
Α	0.460	0.483	11.68	12.28		
В	0.307	0.323	7.80	8.20		
С	0.030	0.033	0.75	0.85		
D	0.071	0.081	1.80	2.05		
Е	1.488	1.504	37.80	38.20		
F	1.248	1.260	31.70	32.00		
G	0.917	0.957	23.30	24.30		
Н	0.996	1.008	25.30	25.60		
I	0.579	0.602	14.70	15.30		
J	0.492	0.516	12.50	13.10		
K	0.161	0.169	4.10	4.30		
L	0.161	0.169	4.10	4.30		
M	0.181	0.197	4.60	5.00		
N	0.165	0.181	4.20	4.60		
0	1.181	1.197	30.00	30.40		
Q	-0.002	0.004	-0.05	0.10		
R	M4*8					

CSRI2×100-065P1B

Electrical Characteristics, at T_i=25 °C, unless otherwise specified. (per diode)

Static Characteristics	Symbol	Conditions	Values			
Static Characteristics			min.	typ.	max.	Unit
DC blocking voltage	V _{DC}		650	-	-	
Diode forward voltage	V _F	I _F =100A, T _j =25 °C	-	1.50	1.70	V
		I _F =100A, T _j =175 °C	-	1.70	2.00	
	IR	V _R =650V, T _j =25 °C	-	60	100	
Reverse current	IR	V _R =650V, T _j =175 °C	-	100	500	μ A

AC Characteristics (per diode)

Static Characteristics	Symbol	Conditions	Values			
Static Characteristics			min.	typ.	max.	Unit
Total capacitive charge	Q _{rr}	V _R =400V, T _j =25 °C	-	300	-	nC
	С	V _R =0V, f=1 MHz T _j =25 °C	-	4500	-	pF
Total capacitance		V _R =200V, f=100 KHz T _j =25 °C	-	513	-	
		V _R =400V, f=100 KHz T _j =25 °C	-	468	-	

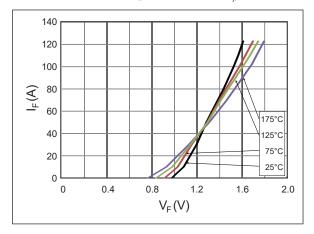
Thermal Characteristics (per diode)

Static Characteristics	Symbol	Values		
Static Characteristics	Symbol	typ.	Unit	
Thermal resistance from junction to case	$R_{ heta JC}$	0.14	°C/W	

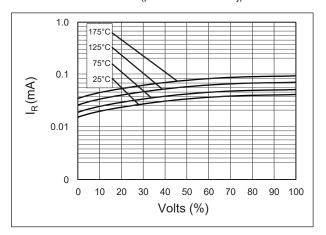
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Typical Performance

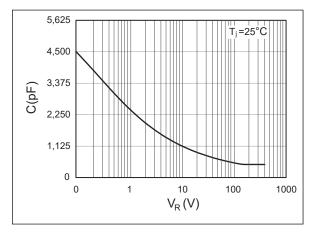
Forward Characteristics (parameterized on T_i)



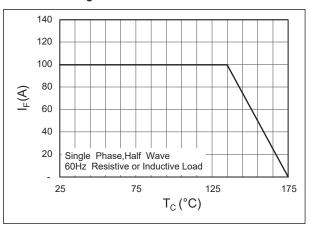
Reverse Characteristics (parameterized on Tj)



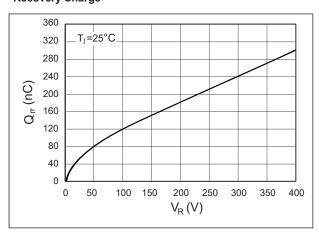
Capacitance



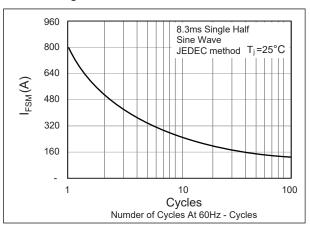
Current Derating



Recovery Charge



Forward Surge Current





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